

MJD32C

Low voltage PNP power transistor

Features

- NPN type is MJD31C
- Surface-mounting TO-252 power package in tape & reel

Applications

■ General purpose switching and amplifier

Description

The device is manufactured in Planar technology with "Base Island" layout. The resulting transistor shows exceptional high gain performance coupled with very low saturation voltage.

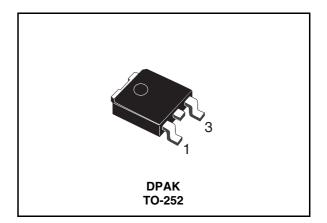
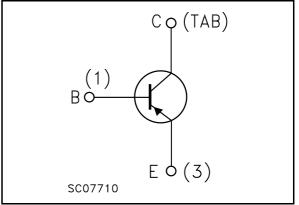


Figure 1. Internal schematic diagram



-	<u> </u>
Table 1.	Order code

Part number Marking		Package	Packaging
MJD32CT4	MJD32C	DPAK	Tape & reel

1/9

1 Electrical ratings

Table 2.	Absolute	maximum	rating
	Aboolato	maximam	. a ung

Symbol	Parameter	Value	Unit
V _{CBO}	Collector-base voltage (I _E = 0)	-100	V
V _{CEO}	Collector-base voltage ($I_B = 0$)	-100	V
V _{EBO}	Emitter-base voltage ($I_C = 0$) -5		V
Ι _C	Collector current	-3	А
I _{CM}	Collector peak current	-5	А
Ι _Β	Base current	-1	А
P _{TOT}	Total dissipation at $T_c = 25^{\circ}C$	15	W
T _{stg}	Storage temperature	-65 to 150	°C
TJ	Max. operating junction temperature	150	°C

2 Electrical characteristics

 $(T_{case} = 25^{\circ}C \text{ unless otherwise specified})$

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
I _{CES}	Collector cut-off current (V _{BE} = 0)	V _{CE} =-100V			-20	μA
I _{CEO}	Collector cut-off current $(I_B = 0)$	V _{CB} =-60V			-50	μA
I _{EBO}	Emitter cut-off current $(I_{\rm C} = 0)$	V _{EB} =-5V			-0.1	mA
V _{CEO(sus)} ⁽¹⁾	Collector-emitter sustaining voltage $(I_B = 0)$	I _C =-30mA	-100			v
V _{CE(sat)} ⁽¹⁾	Collector-emitter saturation voltage	I _C =-3A I _B =-375mA	\		-1.2	V
V _{BE(on)} ⁽¹⁾	Base-emitter on voltage	Itage I _C =-3A V _{CE} =-4V			-1.8	V
h _{FE}	DC current gain	$\begin{array}{c} I_{C} = -1A & V_{CE} = -4V \\ I_{C} = -3A & V_{CE} = -4V \end{array}$	25 10		50	

 Table 3.
 Electrical characteristics

1. Note (1) Pulsed duration = 300 ms, duty cycle £1.5%

Safe operating area

2.1 Electrical characteristic (curves)

Figure 2.

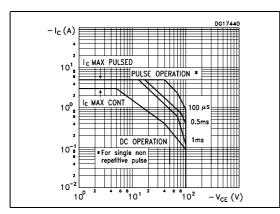


Figure 3. Derating curve

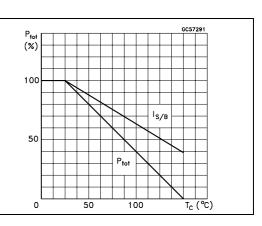
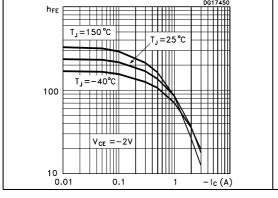
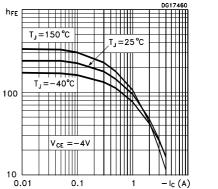


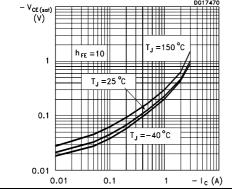
Figure 6.

Figure 4. **DC** current gain Figure 5. DC current gain





Collector-emitter saturation Figure 7. **Base-emitter saturation** voltage – V_{BE(sat)} (V)



voltage

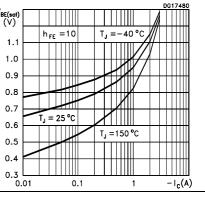
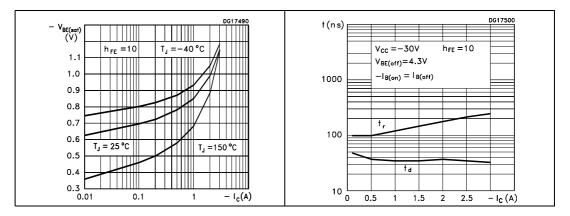


Figure 8. Collector-emitter on voltage Figure 9. **Resistive load switching time**



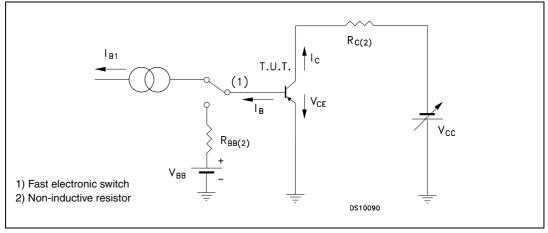


DG17510 t (n s) $V_{CC} = -30V$ $h_{FE} = 10$ V_{BE(off)}=4.3V $-|_{B(on)} = |_{B(off)}$ ts 1000 t_f 100 10 L 0 0.5 1 1.5 2 2.5 $-I_{C}(A)$

Figure 10. Resistive load switching time

2.2 Test circuits







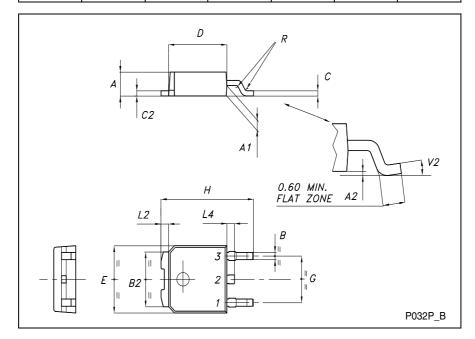
3 Package mechanical data

In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a Lead-free second level interconnect. The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com



DIM.		mm				
Dim.	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
А	2.20		2.40	0.087		0.094
A1	0.90		1.10	0.035		0.043
A2	0.03		0.23	0.001		0.009
В	0.64		0.90	0.025		0.035
B2	5.20		5.40	0.204		0.213
С	0.45		0.60	0.018		0.024
C2	0.48		0.60	0.019		0.024
D	6.00		6.20	0.236		0.244
E	6.40		6.60	0.252		0.260
G	4.40		4.60	0.173		0.181
Н	9.35		10.10	0.368		0.398
L2		0.8			0.031	
L4	0.60		1.00	0.024		0.039
V2	0°		8°	0°		0°

TO-252 (DPAK) MECHANICAL DATA





4 Revision history

Date	Revision	Changes
25-Jun-2007	1	Initial release.



Please Read Carefully:

Information in this document is provided solely in connection with ST products. STMicroelectronics NV and its subsidiaries ("ST") reserve the right to make changes, corrections, modifications or improvements, to this document, and the products and services described herein at any time, without notice.

All ST products are sold pursuant to ST's terms and conditions of sale.

Purchasers are solely responsible for the choice, selection and use of the ST products and services described herein, and ST assumes no liability whatsoever relating to the choice, selection or use of the ST products and services described herein.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted under this document. If any part of this document refers to any third party products or services it shall not be deemed a license grant by ST for the use of such third party products or services, or any intellectual property contained therein or considered as a warranty covering the use in any manner whatsoever of such third party products or services or any intellectual property contained therein.

UNLESS OTHERWISE SET FORTH IN ST'S TERMS AND CONDITIONS OF SALE ST DISCLAIMS ANY EXPRESS OR IMPLIED WARRANTY WITH RESPECT TO THE USE AND/OR SALE OF ST PRODUCTS INCLUDING WITHOUT LIMITATION IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION), OR INFRINGEMENT OF ANY PATENT, COPYRIGHT OR OTHER INTELLECTUAL PROPERTY RIGHT.

UNLESS EXPRESSLY APPROVED IN WRITING BY AN AUTHORIZE REPRESENTATIVE OF ST, ST PRODUCTS ARE NOT RECOMMENDED, AUTHORIZED OR WARRANTED FOR USE IN MILITARY, AIR CRAFT, SPACE, LIFE SAVING, OR LIFE SUSTAINING APPLICATIONS, NOR IN PRODUCTS OR SYSTEMS, WHERE FAILURE OR MALFUNCTION MAY RESULT IN PERSONAL INJURY, DEATH, OR SEVERE PROPERTY OR ENVIRONMENTAL DAMAGE. ST PRODUCTS WHICH ARE NOT SPECIFIED AS "AUTOMOTIVE GRADE" MAY ONLY BE USED IN AUTOMOTIVE APPLICATIONS AT USER'S OWN RISK.

Resale of ST products with provisions different from the statements and/or technical features set forth in this document shall immediately void any warranty granted by ST for the ST product or service described herein and shall not create or extend in any manner whatsoever, any liability of ST.

ST and the ST logo are trademarks or registered trademarks of ST in various countries.

Information in this document supersedes and replaces all information previously supplied.

The ST logo is a registered trademark of STMicroelectronics. All other names are the property of their respective owners.

© 2007 STMicroelectronics - All rights reserved

STMicroelectronics group of companies

Australia - Belgium - Brazil - Canada - China - Czech Republic - Finland - France - Germany - Hong Kong - India - Israel - Italy - Japan -Malaysia - Malta - Morocco - Singapore - Spain - Sweden - Switzerland - United Kingdom - United States of America

www.st.com

